NSN 5961-01-573-3600

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Voltage Rating In Volts Per Characteristic:
17.1 breakdown voltage, dc and 18.0 breakdown voltage, dc
Product Name:
Transient voltage suppresor
Special Features:
1500 watt peak pulse power dissipation (pppm) cababilty; lead free
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

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